

Absolute Maximum Ratings

(Voltages Referenced to GND)

V_{IN}	-0.3V to +6V
Output Short-Circuit Duration to GND or V_{IN}	Continuous
Continuous Power Dissipation ($T_A = +70^\circ\text{C}$)	
3-Pin SOT23 (derate 4.0mW/ $^\circ\text{C}$ above $+70^\circ\text{C}$)	320mW

Operating Temperature Range	-40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Electrical Characteristics (MAX6018_12-1.263V)

($V_{IN} = 1.8\text{V}$; $C_{OUT} = 47\text{nF}$, $I_{OUT} = 0$; $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ\text{C}$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT						
Output Voltage	V_{OUT}	MAX6018A_12 (0.2%)	1.2605	1.2630	1.2655	V
		MAX6018B_12 (0.4%)	1.2580	1.2630	1.2681	
Output Voltage Temperature Drift	TCV_{OUT}	(Note 2)		16	50	ppm/ $^\circ\text{C}$
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$1.8\text{V} \leq V_{IN} \leq 5.5\text{V}$		50	400	$\mu\text{V/V}$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	$0 \leq I_{OUT} \leq 1\text{mA}$		90	700	$\mu\text{V/mA}$
		$-100\mu\text{A} \leq I_{OUT} \leq 0$		2	9	$\mu\text{V}/\mu\text{A}$
Short-Circuit Current	I_{SC}	Sourcing to GND		3		mA
		Sinking from V_{IN}		6		
Long-Term Stability	$\Delta V_{OUT}/\Delta$ Time	1000hrs at $T_A = +25^\circ\text{C}$		100		ppm
Thermal Hysteresis		(Note 4)		130		ppm
DYNAMIC CHARACTERISTICS						
Noise Voltage	e_{OUT}	0.1Hz to 10Hz		45		μV_{p-p}
		10Hz to 10kHz		100		μVRMS
Ripple Rejection		$V_{IN} = 1.8\text{V} \pm 100\text{mV}$ ($f = 120\text{Hz}$)		85		dB
Turn-On Settling Time	t_R	Settling to 0.1%; $C_{OUT} = 5\text{nF}$		200		μs
Capacitive-Load Stability Range	C_{OUT}	(Note 2)	47	1000		nF
INPUT						
Supply Voltage Range	V_{IN}	Guaranteed by Line Regulation Test	1.8	5.5		V
Quiescent Supply Current	I_{IN}	$T_A = +25^\circ\text{C}$		3	5	μA
		$T_A = T_{MIN}$ to T_{MAX}		3	6	
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$1.8\text{V} \leq V_{IN} \leq 5.5\text{V}$		0.1	0.5	$\mu\text{A/V}$

MAX6018

Precision, Micropower, 1.8V Supply,
Low-Dropout, SOT23 Voltage Reference

Electrical Characteristics (MAX6018_16–1.600V)

($V_{IN} = 1.8V$; $C_{OUT} = 47nF$, $I_{OUT} = 0$; $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT						
Output Voltage	V_{OUT}	$MAX6018A_16$ (0.2%)	$T_A = +25^{\circ}C$	1.5968	1.6000	1.6032
		$MAX6018B_16$ (0.4%)	$T_A = +25^{\circ}C$	1.5936	1.6000	1.6064
Output Voltage Temperature Drift	TCV_{OUT}	(Note 2)		16	50	ppm/ $^{\circ}C$
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$1.8V \leq V_{IN} \leq 5.5V$		40	250	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	$0 \leq I_{OUT} \leq 1mA$		90	700	$\mu V/mA$
		$-750\mu A \leq I_{OUT} \leq 0$		0.6	50	$\mu V/\mu A$
Dropout Voltage (Note 3)	$V_{IN} - V_{OUT}$	$I_{OUT} = 1mA$		100	200	mV
Short-Circuit Current	I_{SC}	Sourcing to GND		6		mA
		Sinking from V_{IN}		2		
Long-Term Stability	$\Delta V_{OUT}/Time$	1000hrs at $T_A = +25^{\circ}C$		100		ppm
Thermal Hysteresis		(Note 4)		130		ppm
DYNAMIC CHARACTERISTICS						
Noise Voltage	e_{OUT}	0.1Hz to 10Hz		40		μV_{p-p}
		10Hz to 10kHz		150		μV_{RMS}
Ripple Rejection		$V_{IN} = 1.8V \pm 100mV$ ($f = 120Hz$)		85		dB
Turn-On Settling Time	t_R	Settling to 0.1%; $C_{OUT} = 5nF$		200		μs
Capacitive-Load Stability Range	C_{OUT}	(Note 2)		0.1	1000	nF
INPUT						
Supply Voltage Range	V_{IN}	Guaranteed by Line Regulation Test		1.8	5.5	V
Quiescent Supply Current	I_{IN}	$T_A = +25^{\circ}C$		3	5	μA
		$T_A = T_{MIN}$ to T_{MAX}		3	6	
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$1.8V \leq V_{IN} \leq 5.5V$		0.1	0.5	$\mu A/V$

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Electrical Characteristics (MAX6018_18–1.800V)

($V_{IN} = 2.0V$; $C_{OUT} = 47nF$, $I_{OUT} = 0$; $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^{\circ}C$.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT						
Output Voltage	V_{OUT}	$MAX6018A_18$ (0.2%)	$T_A = +25^{\circ}C$	1.7964	1.8000	1.8036
		$MAX6018B_18$ (0.4%)	$T_A = +25^{\circ}C$	1.7928	1.8000	1.8072
Output Voltage Temperature Drift	TCV_{OUT}	(Note 2)		16	50	ppm/ $^{\circ}C$
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	$2.0V \leq V_{IN} \leq 5.5V$		40	275	$\mu V/V$
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	$0 \leq I_{OUT} \leq 1mA$		90	800	$\mu V/mA$
		$-1mA \leq I_{OUT} \leq 0$		0.4	50	$\mu V/\mu A$
Dropout Voltage (Note 3)	$V_{IN} - V_{OUT}$	$I_{OUT} = 1mA$		100	200	mV
Short-Circuit Current	I_{SC}	Sourcing to GND		7.5		mA
		Sinking from V_{IN}		3		
Long-Term Stability	$\Delta V_{OUT}/$ Time	1000hrs at $T_A = +25^{\circ}C$		100		ppm
Thermal Hysteresis		(Note 4)		130		ppm
DYNAMIC CHARACTERISTICS						
Noise Voltage	e_{OUT}	0.1Hz to 10Hz		45		μV_{p-p}
		10Hz to 10kHz		160		μV_{RMS}
Ripple Rejection		$V_{IN} = 2.0V \pm 100mV$ ($f = 120Hz$)		85		dB
Turn-On Settling Time	t_R	Settling to 0.1%; $C_{OUT} = 5nF$		200		μs
Capacitive-Load Stability Range	C_{OUT}	(Note 2)		0.1	1000	nF
INPUT						
Supply Voltage Range	V_{IN}	Guaranteed by Line Regulation Test		2.0	5.5	V
Quiescent Supply Current	I_{IN}	$T_A = +25^{\circ}C$		3	5	μA
		$T_A = T_{MIN}$ to T_{MAX}		3	6	
Change in Quiescent Supply Current vs. Input Voltage	$\Delta I_{IN}/\Delta V_{IN}$	$2V \leq V_{IN} \leq 5.5V$		0.1	0.5	$\mu A/V$

Electrical Characteristics (MAX6018_21–2.048V)(V_{IN} = 2.25V; C_{OUT} = 47nF, I_{OUT} = 0; T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
OUTPUT						
Output Voltage	V _{OUT}	MAX6018A_21 (0.2%)	T _A = +25°C	2.0439	2.0480	2.0521
		MAX6018B_21 (0.4%)	T _A = +25°C	2.0398	2.0480	2.0562
Output Voltage Temperature Drift	TCV _{OUT}	(Note 2)		16	50	ppm/°C
Line Regulation	ΔV _{OUT} / ΔV _{IN}	2.25V ≤ V _{IN} ≤ 5.5V		45	330	μV/V
Load Regulation	ΔV _{OUT} / ΔI _{OUT}	0 ≤ I _{OUT} ≤ 1mA		90	1000	μV/mA
		-1mA ≤ I _{OUT} ≤ 0		0.3	50	μV/μA
Dropout Voltage (Note 3)	V _{IN} - V _{OUT}	I _{OUT} = 1mA		100	200	mV
Short-Circuit Current	I _{SC}	Sourcing to GND		10		
		Sinking from V _{IN}		4		mA
Long-Term Stability	ΔV _{OUT} / Time	1000hrs at T _A = +25°C		100		ppm
Thermal Hysteresis		(Note 4)		130		ppm
DYNAMIC CHARACTERISTICS						
Noise Voltage	e _{OUT}	0.1Hz to 10Hz		50		μV _{p-p}
		10Hz to 10kHz		175		μV _{RMS}
Ripple Rejection		V _{IN} = 2.25V ±100mV (f = 120Hz)		85		dB
Turn-On Settling Time	t _R	Settling to 0.1%; C _{OUT} = 5nF		200		μs
Capacitive-Load Stability Range	C _{OUT}	(Note 2)		0.1	1000	nF
INPUT						
Supply Voltage Range	V _{IN}	Guaranteed by Line Regulation Test	2.25	5.5		V
Quiescent Supply Current	I _{IN}	T _A = +25°C		3	5	
		T _A = T _{MIN} to T _{MAX}		3	6	μA
Change in Quiescent Supply Current vs. Input Voltage	ΔI _{IN} /ΔV _{IN}	2.25V ≤ V _{IN} ≤ 5.5V		0.1	0.5	μA/V

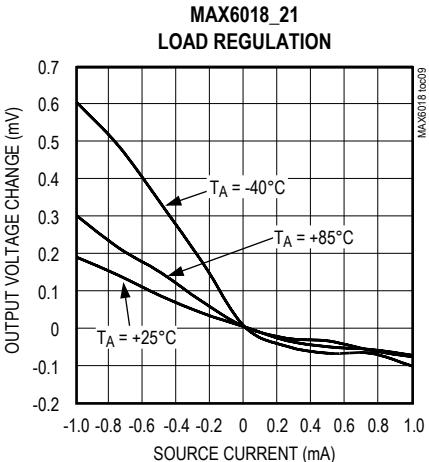
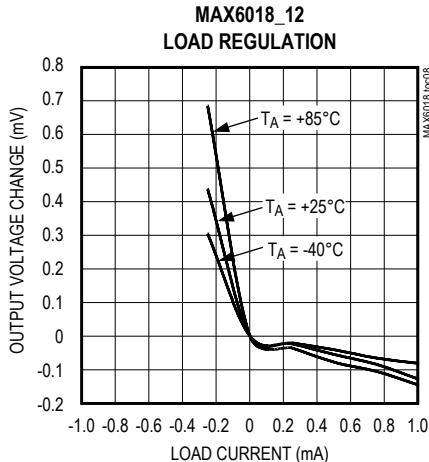
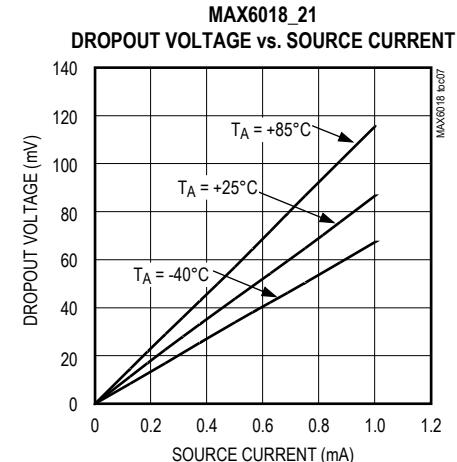
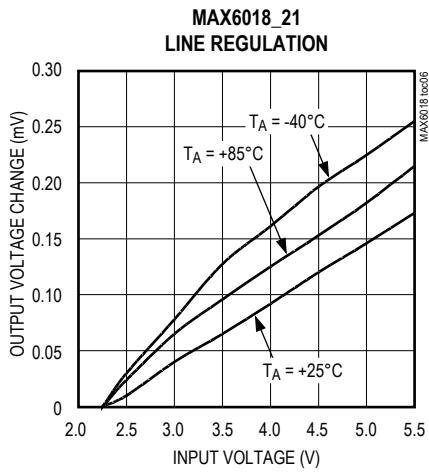
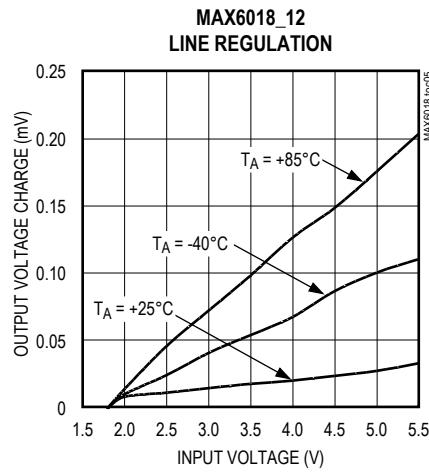
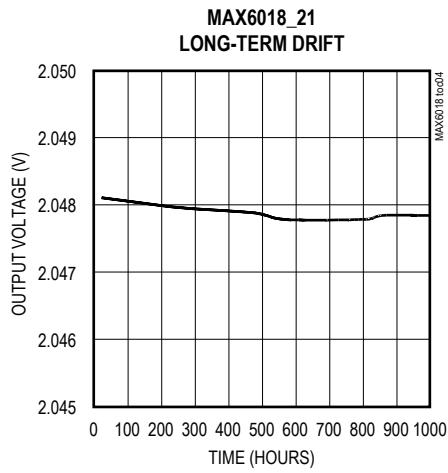
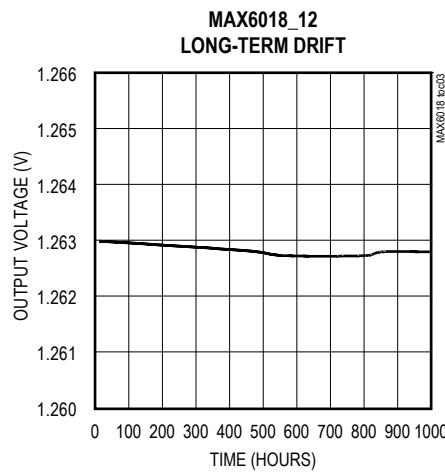
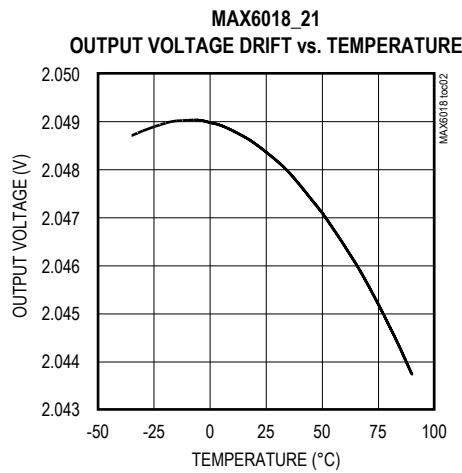
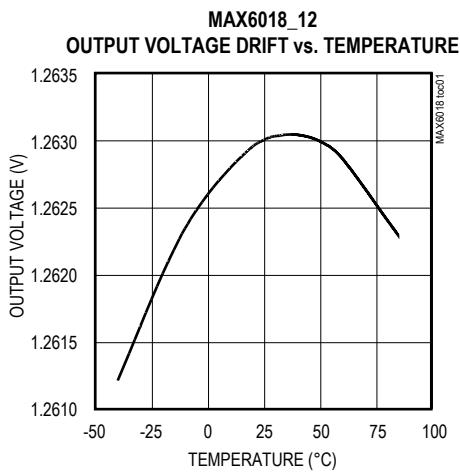
Note 1: Devices are 100% production tested at T_A = +25°C and are guaranteed by design from T_A = T_{MIN} to T_{MAX}.**Note 2:** Not production tested. Guaranteed by design.**Note 3:** Dropout voltage is the minimum input voltage at which V_{OUT} changes ≤ 0.2% from V_{OUT} at rated V_{IN} and is guaranteed by Load Regulation Test.**Note 4:** Thermal hysteresis is defined as the change in T_A = +25°C output voltage before and after temperature cycling of the device (from T_A = T_{MIN} to T_{MAX}). Initial measurement at T_A = +25°C is followed by temperature cycling the device to T_A = +85°C then to T_A = -40°C and another measurement at T_A = +25°C is compared to the original measurement at T_A = +25°C.

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Precision, Micropower, 1.8V Supply,
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Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

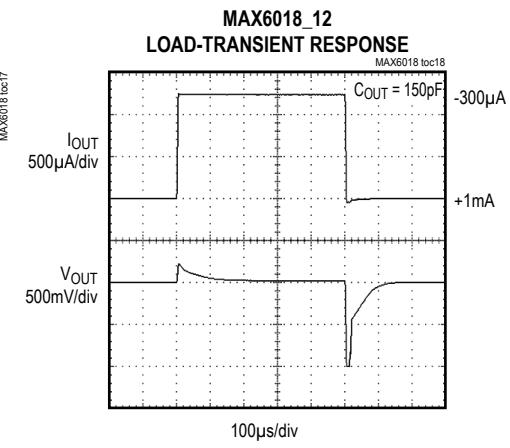
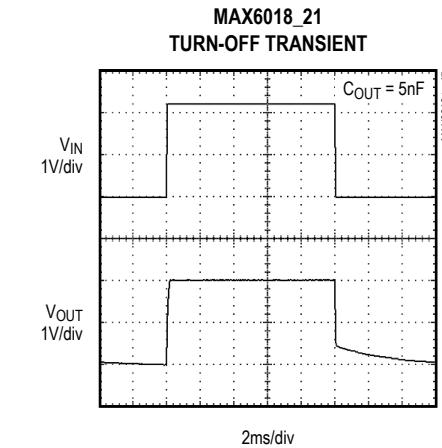
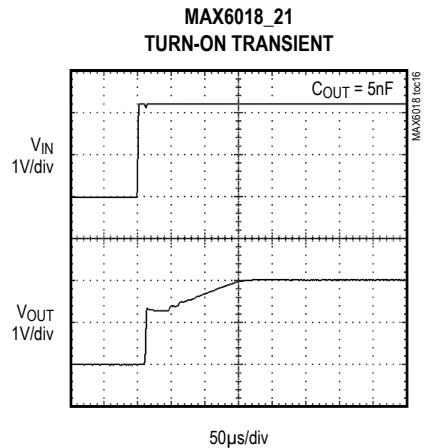
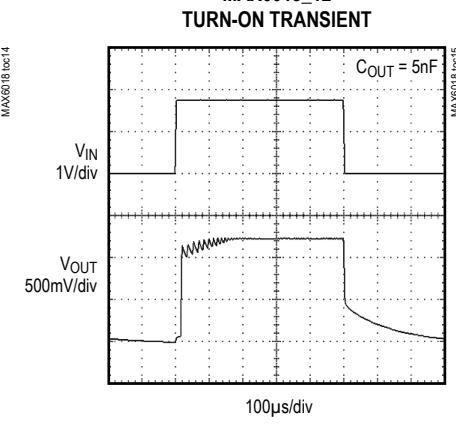
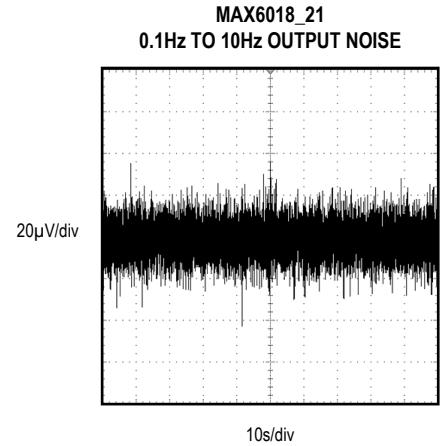
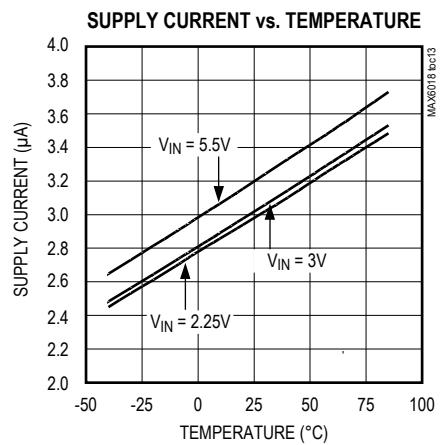
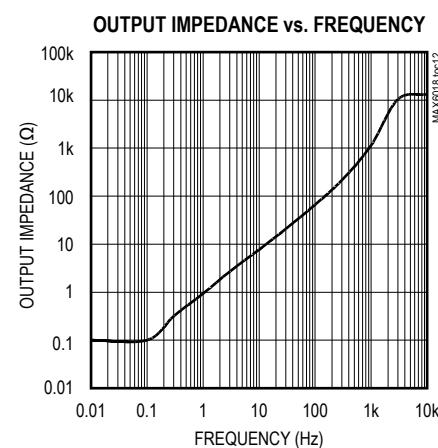
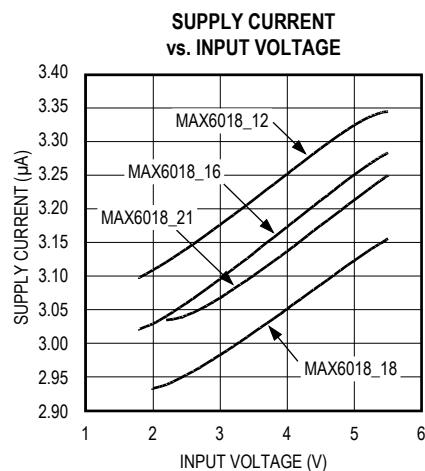
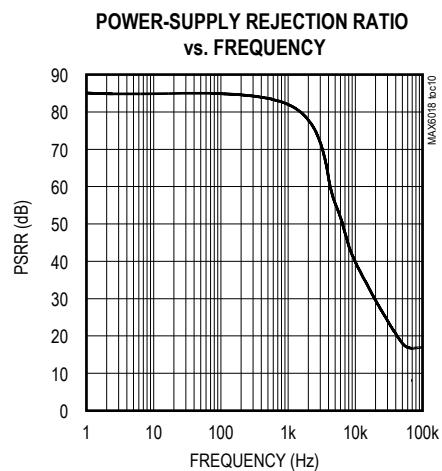


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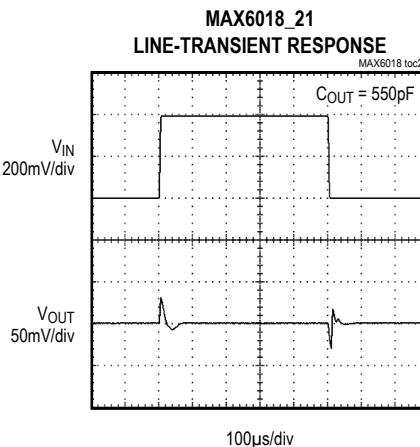
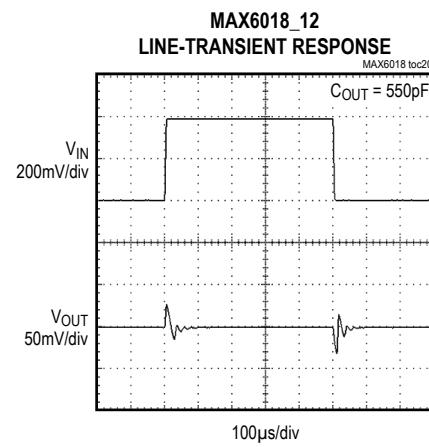
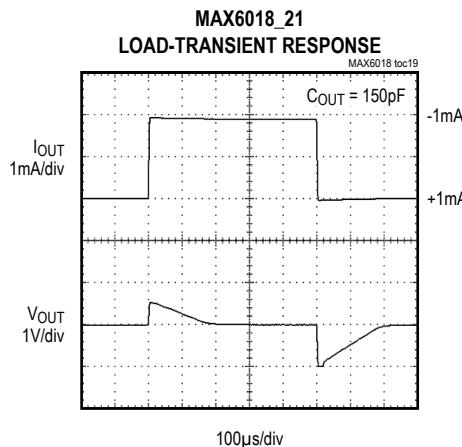
Typical Operating Characteristics (continued)

($T_A = +25^\circ\text{C}$, unless otherwise noted.)



Typical Operating Characteristics (continued)

(TA = +25°C, unless otherwise noted.)

**Detailed Description**

The MAX6018 is a precision, low-voltage, low-dropout, micropower, bandgap voltage reference in a SOT23 package. This three-terminal reference operates with an input voltage from (V_{OUT} + 200mV) to 5.5V, and is available with output voltage options of 1.2V, 1.6V, 1.8V, and 2.048V. These devices can source up to 1mA with <200mV of dropout voltage, making them attractive for use in low-voltage applications.

Applications Information**Output/Load Capacitance**

These devices require a minimum of 100pF load to maintain output stability.

They remain stable for capacitive loads as high as 1μF. In applications where the load or the supply can experience step changes, a larger output capacitor reduces the amount of overshoot (or undershoot) and assists the circuit's transient response. Otherwise, applications may not need more than 100pF.

Supply Current

The 5μA maximum supply current varies only 0.1μA/V with the supply voltage.

When the supply voltage is below the minimum-specified input voltage (as during turn-on), the devices can draw up to 20μA beyond the nominal supply current. The input voltage source must be capable of providing this current to ensure reliable turn-on.

Pin Description

PIN	NAME	FUNCTION
1	IN	Supply Voltage Input. Bypass with a 0.1μF capacitor to ground.
2	OUT	Reference Voltage Output. Bypass with at least 100pF to ground. (See <i>Output/Load Capacitance</i> section).
3	GND	Ground

Turn-On Time

These devices typically turn on and settle to within 0.1% of their final value in 200μs. The turn-on time can increase up to 1ms with the device operating at the minimum dropout voltage and the maximum load.

Package Information

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a “+”, “#”, or “-” in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
3 SOT23	U3+1	21-0051	90-0179

Chip Information

TRANSISTOR COUNT: 87

PROCESS: BiCMOS

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
3	10/15	Added lead-free options	1

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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